LISTING OF THE CLAIMS:

- 1. (Currently Amended) An electronic device, comprising:
- a semiconductor chip having a first surface in electrical communication with a substrate;

a heat spreader being arrayed in closely spaced relationship with an opposite surface of said semiconductor chip; and

adhesive means bonding said heat spreader to said semiconductor chip, said adhesive means comprising an electrically conductive <u>silicone</u> adhesive positioned <u>in an essentially single spot</u> on a center or an areal surface portion of said semiconductor chip, and an electrically non-conductive <u>silicone</u> adhesive <u>of an extensively larger surface area than said single spot formed by said electrically conductive silicone adhesive</u> extending about said electrically conductive <u>silicone</u> adhesive for concurrently bonding said heat spreader to said semiconductor chip.

- 2. (Original) An electronic device, as claimed in Claim 1, wherein said heat spreader comprises an electrically conductive material forming an electrical connection with said semiconductor chip through said electrically conductive adhesive.
- 3. (Original) An electronic device, as claimed in Claim 1, wherein said heat spreader a constituted of a heat-absorbing and dissipating material.

- 4. (Original) An electronic device, as claimed in Claim 2, wherein said heat spreader is selected from the group of materials consisting of copper, silver, aluminum, alumina or alumina silica carbide.
- 5. (Original) An electronic device, as claimed in Claim 1, wherein said heat spreader comprises a plate-shaped lid or cap member adhesively bonded to said semiconductor chip.
- 6. (Currently Amended) An electronic device, as claimed in Claim 1, wherein said electrically conductive <u>silicone</u> adhesive electrically connecting <u>connects</u> said heat spreader and said semiconductor chip.
- 7. (Currently Amended) An electronic device, as claimed in Claim 1, wherein said electrically non-conductive <u>silicone</u> adhesive comprises a thermally conductive <u>silicone</u> adhesive for conveying heat from said semiconductor chip to said heat spreader.
- 8. (Original) An electronic device, as claimed in Claim 1, wherein said electrically conductive adhesive is deposited on the areal surface portion of said semiconductor chip surface to form an about 1 mm diameter bond area with said heat spreader.
- 9. (Original) An electronic device, as claimed in Claim 8, wherein said electrically non-conductive adhesive is deposited on said semiconductor chip so as to cover the remaining surface area of said chip extending about said electrically conductive adhesive.

- 10. (Original) An electronic device, as claimed in Claim 8, wherein said heat spreader is spaced from said semiconductor chip to provide a bondline thickness of about 0.025 mm to 0.15 mm for said adhesives.
- 11. (Currently Amended) A method of forming an electronic device, said method comprising:

providing a semiconductor chip having a first surface in electrical communication with a substrate;

arranging a heat spreader in closely spaced relationship with an opposite surface of said semiconductor chip; and

having adhesive means bond said heat spreader to said semiconductor chip, said adhesive means comprising an electrically conductive <u>silicone</u> adhesive positioned <u>in an essentially single spot formed by said electrically conductive silicone adhesive</u> on a center or an areal surface portion of said semiconductor chip, and an electrically non-conductive <u>silicone</u> adhesive <u>of an extensively larger surface area than said single spot</u> extending about said electrically conductive <u>silicone</u> adhesive for concurrently bonding said heat spreader to said semiconductor chip.

12. (Original) A method, as claimed in Claim 11, wherein said heat spreader comprises an electrically conductive material forming an electrical connection with said semiconductor chip through said electrically conductive adhesive.

- 13. (Original) A method, as claimed in Claim 11, wherein said heat spreader is constituted of a metallic heat-absorbing and dissipating material.
- 14. (Original) A method, as claimed in Claim 12, wherein said heat spreader is selected from the group of materials consisting of copper, silver, aluminum, alumina or alumina silica carbide.
- 15. (Original) A method, as claimed in Claim 11, wherein said heat spreader comprises a plate-shaped lid or cap member adhesively bonded to said semiconductor chip.
- 16. (Currently Amended) A method, as claimed in Claim 11, wherein said electrically conductive <u>silicone</u> adhesive comprises a <u>silicone</u> adhesive electrically connecting connects said heat spreader and said semiconductor chip.
- 17. (Currently Amended) A method, as claimed in Claim 11, wherein said electrically non-conductive <u>silicone</u> adhesive comprises a thermally conductive <u>silicone</u> adhesive for conveying heat from said semiconductor chip to said heat spreader.
- 18. (Original) A method, as claimed in Claim 11, wherein said electrically conductive adhesive is deposited on the areal surface portion of said semiconductor chip surface to form an about 1 mm diameter bond area with said heat spreader.

- 19. (Original) A method, as claimed in Claim 18, wherein said electrically non-conductive adhesive is deposited on said semiconductor chip so as to cover the remaining surface area of said chip extending about said electrically conductive adhesive.
- 20. (Original) A method, as claimed in Claim 18, wherein said heat spreader is spaced from said semiconductor chip to provide a bondline thickness of about 0.025 mm to 0.15 mm for said adhesives.